

## POWER SCHOTTKY RECTIFIER

PRELIMINARY DATASHEET

### MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	<b>2 x 40 A</b>
$V_{RRM}$	<b>60 V</b>
$T_j(\text{max})$	<b>150 °C</b>
$V_F(\text{max})$	<b>0.56 V</b>

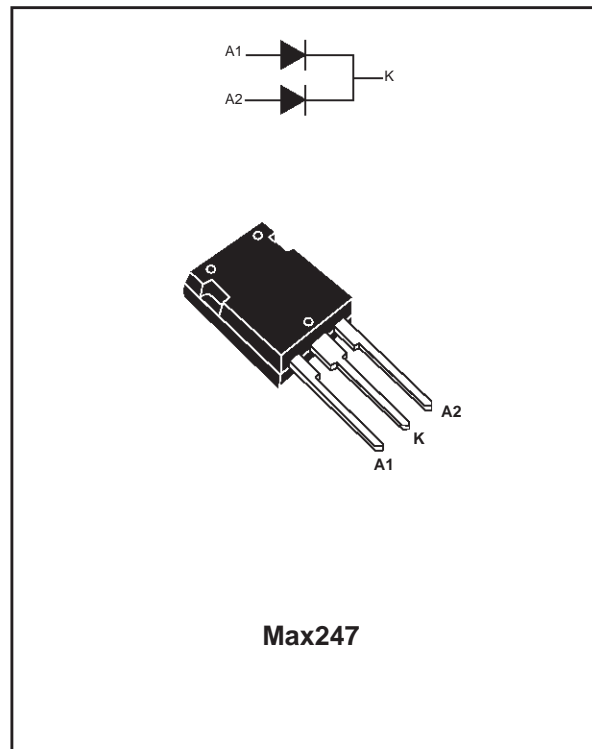
### FEATURES AND BENEFITS

- VERY SMALL CONDUCTION LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- EXTREMELY FAST SWITCHING
- LOW FORWARD VOLTAGE DROP
- LOW THERMAL RESISTANCE

### DESCRIPTION

Dual center tap Schottky rectifier suited for CAD computers and servers.

Packaged in Max247, this device is intended for use in low voltage, high frequency switching power supplies, free wheeling and polarity protection applications.



### ABSOLUTE RATINGS (limiting values, per diode)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage		60	V
$I_{F(RMS)}$	RMS forward current		50	A
$I_{F(AV)}$	Average forward current	$T_c = 130^\circ\text{C}$ $\delta = 0.5$	Per diode 40	A
			Per device 80	
$I_{FSM}$	Surge non repetitive forward current	$t_p = 10 \text{ ms}$ sinusoidal	400	A
$I_{RRM}$	Repetitive peak reverse current	$t_p = 2 \mu\text{s}$ square F = 1kHz	2	A
$T_{stg}$	Storage temperature range		- 65 to + 150	°C
$T_j$	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/ $\mu\text{s}$

\* :  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  thermal runaway condition for a diode on its own heatsink

## STPS80L60CY

### THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case	Per diode	0.70	°C/W
		Total	0.50	
R <sub>th(c)</sub>		Coupling	0.3	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode 1}) = P(\text{diode 1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

### STATIC ELECTRICAL CHARACTERISTICS (per diode)

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub> *	Reverse leakage current	T <sub>j</sub> = 25°C	V <sub>R</sub> = V <sub>RRM</sub>			1.8	mA
		T <sub>j</sub> = 125°C			0.4	0.9	A
V <sub>F</sub> *	Forward voltage drop	T <sub>j</sub> = 25°C	I <sub>F</sub> = 40 A			0.57	V
		T <sub>j</sub> = 125°C	I <sub>F</sub> = 40 A		0.50	0.56	
		T <sub>j</sub> = 25°C	I <sub>F</sub> = 80 A			0.78	
		T <sub>j</sub> = 125°C	I <sub>F</sub> = 80 A		0.69	0.77	

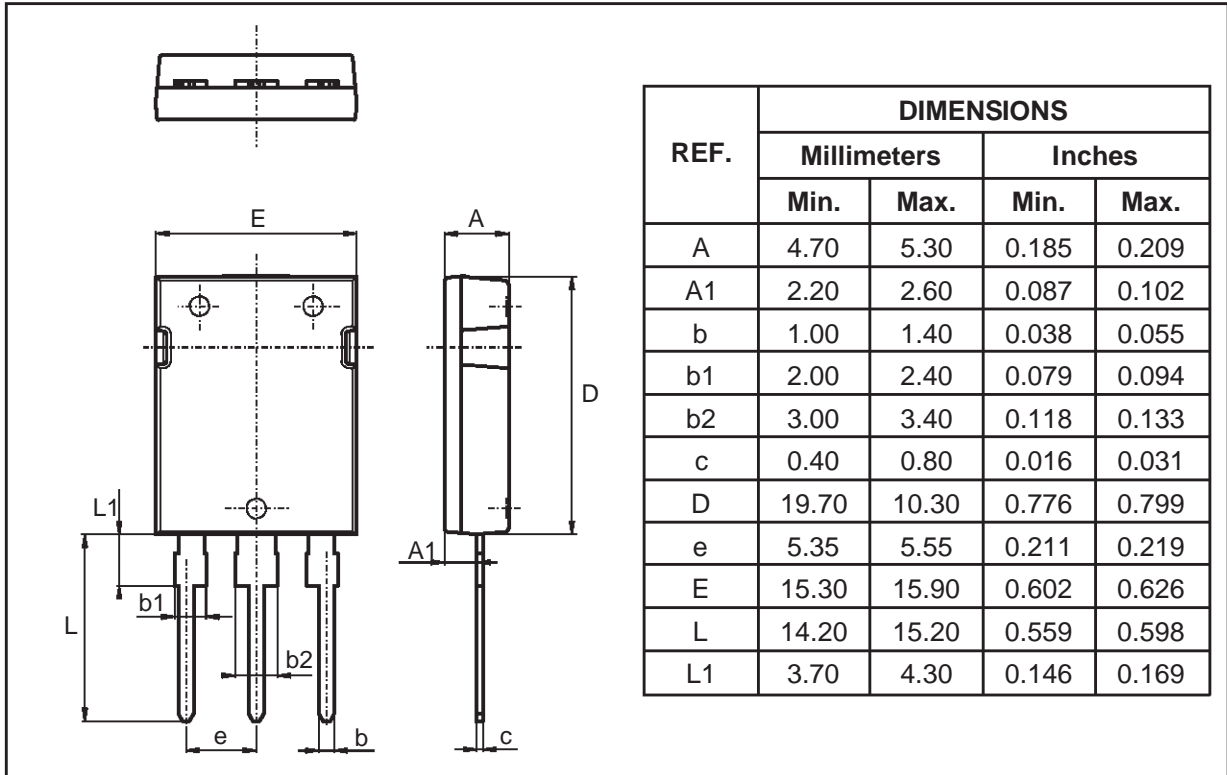
Pulse test : \* t<sub>p</sub> = 380 μs, δ < 2%

To evaluate the maximum conduction losses use the following equation :

$$P = 0.36 \times I_{F(AV)} + 0.005 \times I_{F(RMS)}^2$$

## PACKAGE MECHANICAL DATA

Max247



Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS80L60CY	STPS80L60CY	Max247	4.4g	30	Tube

■ Epoxy meets UL94,V0

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